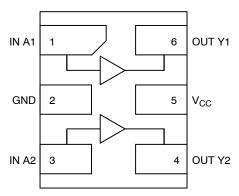
# **Dual Buffer**

The NLX2G16 MiniGate<sup>™</sup> is an advanced high-speed CMOS dual non-inverting buffer in ultra-small footprint.

The NLX2G16 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

## Features

- High Speed:  $t_{PD} = 1.8 \text{ ns} (Typ) @ V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Low Power Dissipation:  $I_{CC} = 1 \ \mu A$  (Max) at  $T_A = 25^{\circ}C$
- 24 mA Balanced Output Source and Sink Capability
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



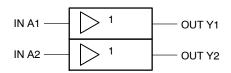


Figure 2. Logic Symbol

#### **PIN ASSIGNMENT**

FUNCTIO	N TABLE
Α	Y
L	L

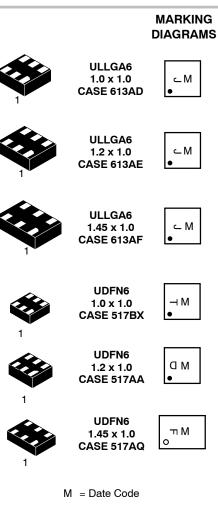
н

	1	IN A1
	2	GND
ABLE	3	IN A2
Y	4	OUT Y2
L	5	V <sub>CC</sub>
Н	6	OUT Y1



# **ON Semiconductor®**

http://onsemi.com



## **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

## MAXIMUM RATINGS

Symbol	Paramet	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage		-0.5 to +7.0	V
Ι <sub>ΙΚ</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current	±50	mA	
I <sub>CC</sub>	DC Supply Current Per Supply Pin		±100	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Second	econds	260	°C
TJ	Junction Temperature Under Bias	150	°C	
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating Oxygen	Index: 28 to 34	UL 94 V-0 @ 0.125 in	
I <sub>LATCHUP</sub>	Latchup Performance Above $V_{CC}$ and Below	GND at 125 °C (Note 5)	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/UESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	Digital Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free–Air Temperature		-55	+125	°C
$\Delta t/\Delta V$	V <sub>CC</sub> = V <sub>CC</sub> =	= 1.8 V ± 0.18 2.5 V ± 0.2 V 3.3 V ± 0.3 V 5.0 V ± 0.5 V	0 0 0 0	20 20 10 5	ns/V

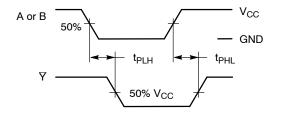
## DC ELECTRICAL CHARACTERISTICS

			Vee	$V_{CC}$ $T_A = 25 °C$		T <sub>A</sub> = +	⊦85°C	T <sub>A</sub> = -{ +12			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	Low-Level Input Voltage		1.65–1.95	0.75 x V <sub>CC</sub>			0.75 x V <sub>CC</sub>		0.75 x V <sub>CC</sub>		V
	vollage		2.3 to 5.5	0.70 x V <sub>CC</sub>			0.70 x V <sub>CC</sub>		0.70 x V <sub>CC</sub>		
V <sub>IL</sub>	Low-Level Input		1.65–1.95			0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>	V
	Voltage		2.3 – 5.5			0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>	
V <sub>OH</sub>	High– Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \ \mu A$	1.65 – 5.5	V <sub>CC</sub> - 0.1	V <sub>CC</sub>		V <sub>CC</sub> - 0.1		V <sub>CC</sub> - 0.1		V
	Voltage		1.65 2.3 3.0 3.0 4.5	1.29 1.9 2.4 2.3 3.8	1.52 2.15 2.8 2.68 4.2		1.29 1.9 2.4 2.3 3.8		1.29 1.9 2.4 2.3 3.8		
V <sub>OL</sub>	Low-Level Output	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 100 \ \mu A$	1.65 – 5.5			0.1		0.1		0.1	V
	Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$	1.65 2.3 3.0 3.0 4.5		0.08 0.1 0.15 0.22 0.22	0.24 0.3 0.4 0.55 0.55		0.24 0.3 0.4 0.55 0.55		0.24 0.3 0.4 0.55 0.55	
l <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I <sub>OFF</sub>	Power-Off Output Leakage Current	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	0			1.0		10		10	μΑ
Icc	Quiescent Supply Current	$V_{IN} = 0 V \text{ or } V_{CC}$	5.5			1.0		10		10	μΑ

		V <sub>CC</sub>	Test	т	A = 25 °	с	T <sub>A</sub> = - to +1		
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay Input A to Output	1.65–1.95	$R_L = 1 M\Omega$ , $C_L = 15 pF$	1.8	8.0	9.6	1.8	10.2	ns
		2.3–2.7	$R_L = 1 M\Omega,$ $C_L = 15 pF$	1.0	3.0	5.2	1.0	5.8	
		3.0–3.6	R <sub>L</sub> = 1 MΩ, C <sub>L</sub> = 15 pF	0.8	2.3	3.6	0.8	4.0	
			R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 50 pF	1.2	3.0	4.6	1.2	5.1	
		4.5–5.5	$R_L = 1 MΩ,$ $C_L = 15 pF$	0.5	1.8	2.9	0.5	3.2	
			R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 50 pF	0.8	2.4	3.8	0.8	4.2	
C <sub>IN</sub>	Input Capacitance	5.5	$V_{IN} = 0 V \text{ or } V_{CC}$		7.0				pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	3.3 5.5	10 MHz $V_{IN}$ = 0 V or $V_{CC}$		9 11				pF

## **AC ELECTRICAL CHARACTERISTICS** (Input $t_r = t_f = 3.0 \text{ nS}$ )

6.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .



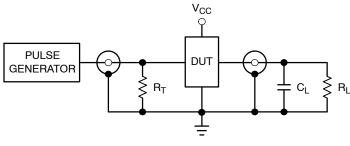


Figure 3. Switching Waveforms

 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

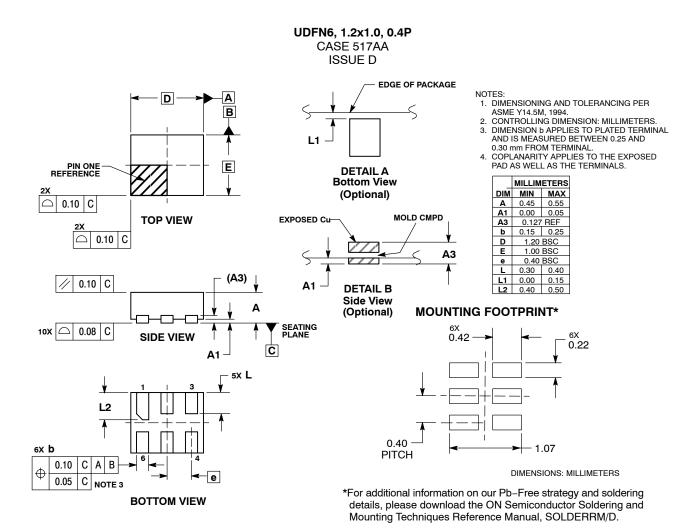
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLX2G16AMX1TCG	ULLGA6, 1.45 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel
NLX2G16BMX1TCG	ULLGA6, 1.2 x 1.0, 0.4P (Pb–Free)	3000 / Tape & Reel
NLX2G16CMX1TCG	ULLGA6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel
NLX2G16MUTCG (In Development)	UDFN6, 1.2 x 1.0, 0.4P (Pb-Free)	3000 / Tape & Reel
NLX2G16AMUTCG, NLVX2G16AMUTCG*	UDFN6, 1.45 x 1.0, 0.5P (Pb–Free)	3000 / Tape & Reel
NLX2G16CMUTCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel

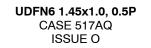
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

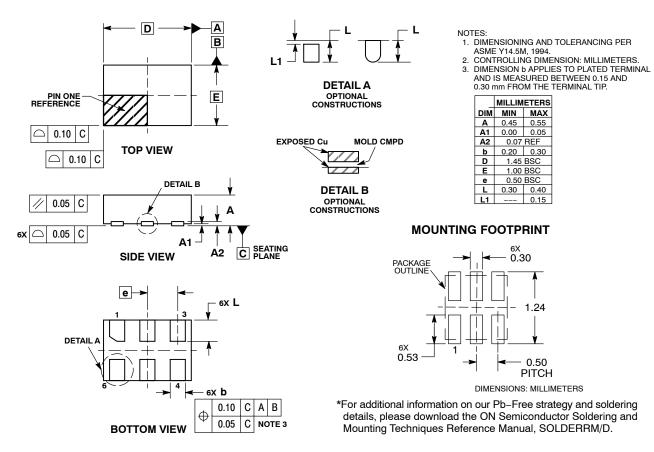
\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

### PACKAGE DIMENSIONS



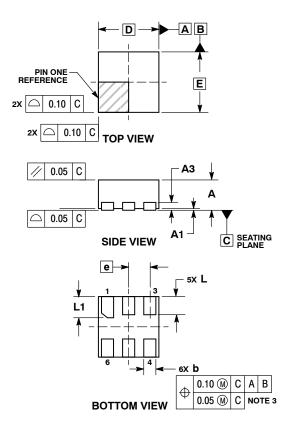
### PACKAGE DIMENSIONS





## PACKAGE DIMENSIONS

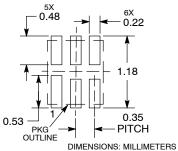
UDFN6 1.0x1.0, 0.35P CASE 517BX ISSUE O



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.13	REF			
b	0.12	0.22			
D	1.00	BSC			
Е	1.00	BSC			
е	0.35	BSC			
L	0.25	0.35			
L1	0.30	0.40			

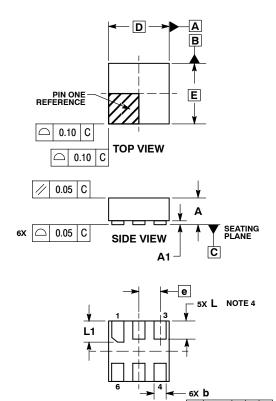
# RECOMMENDED SOLDERING FOOTPRINT\*



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### PACKAGE DIMENSIONS

ULLGA6 1.0x1.0, 0.35P CASE 613AD **ISSUE A** 



**BOTTOM VIEW** 

0.10 C A B

0.05 C NOTE 3

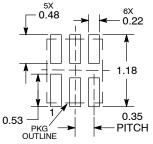
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NOTES:

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP. 4. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALL OWED
- PACKAGE IS ALLOWED.

	MILLIMETERS				
DIM	MIN	MAX			
Α		0.40			
A1	0.00	0.05			
b	0.12	0.22			
D	1.00	BSC			
Е	1.00	BSC			
е	0.35	BSC			
L	0.25	0.35			
L1	0.30	0.40			

#### **MOUNTING FOOTPRINT** SOLDERMASK DEFINED\*

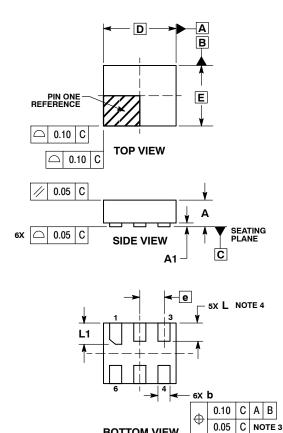


DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

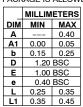
ULLGA6 1.2x1.0, 0.4P CASE 613AE **ISSUE A** 



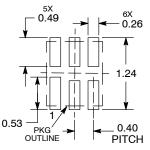
**BOTTOM VIEW** 

NOTES:

- NOTES:
   DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
   DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.
   A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.



#### MOUNTING FOOTPRINT SOLDERMASK DEFINED\*

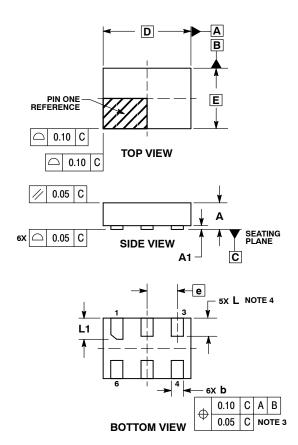


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#### PACKAGE DIMENSIONS

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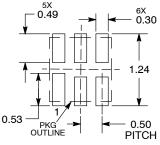


NOTES

- DIMENSIONING AND TOLERANCING PER 1.
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MESAURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP. 2. 3.
- A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

	MILLIMETERS				
DIM	MIN	MAX			
Α		0.40			
A1	0.00	0.05			
b	0.15	0.25			
D	1.45 BSC				
Е	1.00 BSC				
е	0.50 BSC				
L	0.25	0.35			
L1	0.30	0.40			

MOUNTING FOOTPRINT SOLDERMASK DEFINED\*



DIMENSIONS: MILLIMETERS

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